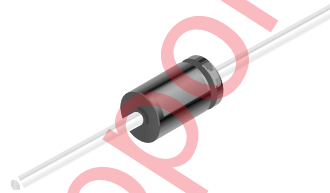




# 1N4933GP - 1N4937GP

## Features

- Low forward voltage drop.
- High surge current capability.
- High reliability.
- High current capability.



**DO-41**  
COLOR BAND DENOTES CATHODE

## Fast Rectifiers (Glass Passivated)

### Absolute Maximum Ratings\*

$T_A = 25^\circ\text{C}$  unless otherwise noted

Symbol	Parameter	Value					Units
		4933G	4934	4935	4936	4937	
$V_{RRM}$	Maximum Repetitive Reverse Voltage	50	100	200	400	600	V
$I_{F(AV)}$	Average Rectified Forward Current, .375 " lead length @ $T_A = 75^\circ\text{C}$	1.0					A
$I_{FSM}$	Non-repetitive Peak Forward Surge Current 8.3 ms Single Half-Sine-Wave	30					A
$T_{stg}$	Storage Temperature Range	-65 to +175					$^\circ\text{C}$
$T_J$	Operating Junction Temperature	-65 to +175					$^\circ\text{C}$

\*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

### Thermal Characteristics

Symbol	Parameter	Value	Units
$P_D$	Power Dissipation	2.73	W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	55	$^\circ\text{C}/\text{W}$

### Electrical Characteristics

$T_A = 25^\circ\text{C}$  unless otherwise noted

Symbol	Parameter	Device					Units
		4933G	4934	4935	4936	4937	
$V_F$	Forward Voltage @ 1.0 A	1.2					V
$t_{rr}$	Reverse Recovery Time $I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A}, I_{rr} = 0.25 \text{ A}$	150					ns
$I_R$	Reverse Current @ rated $V_R$ $T_A = 25^\circ\text{C}$ $T_A = 125^\circ\text{C}$	5.0 100					$\mu\text{A}$ $\mu\text{A}$
$C_T$	Total Capacitance $V_R = 4.0 \text{ V}, f = 1.0 \text{ MHz}$	15					pF

## Typical Characteristics

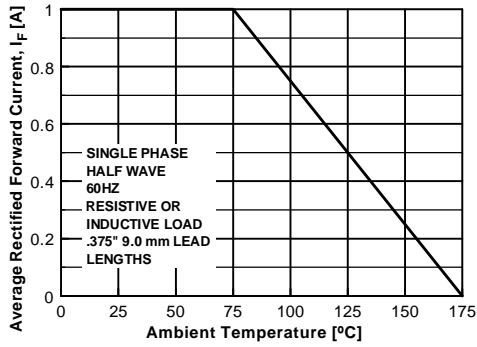


Figure 1. Forward Current Derating Curve

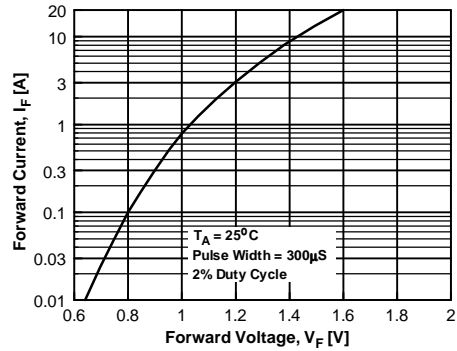


Figure 2. Forward Voltage Characteristics  
Reverse Characteristics

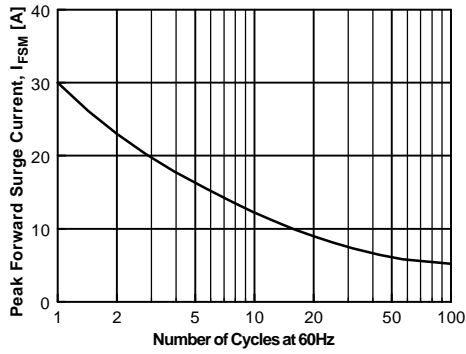


Figure 3. Non-Repetitive Surge Current

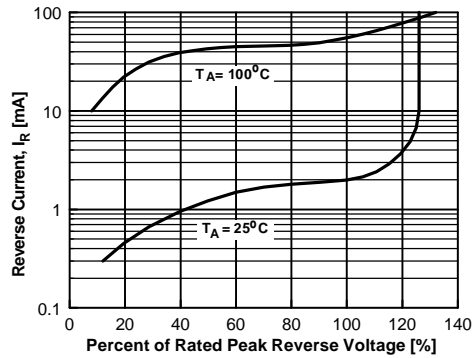


Figure 4. Reverse Current vs Reverse Voltage

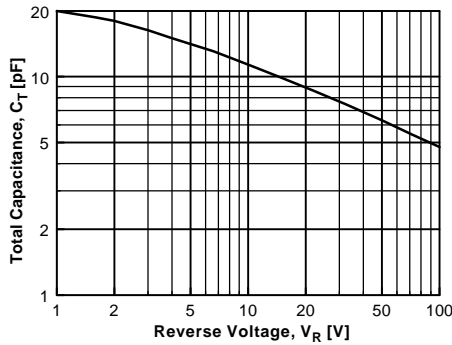
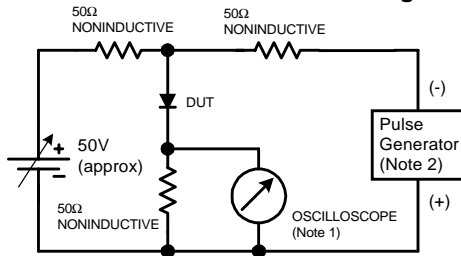
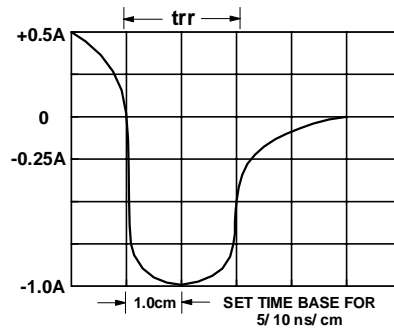


Figure 5. Total Capacitance



NOTES:

1. Rise time = 7.0 ns max; Input impedance = 1.0 megaohm 22 pf.
2. Rise time = 10 ns max; Source impedance = 50 ohms.



Reverse Recovery Time Characteristic and Test Circuit Diagram

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